RECEIVED

NOV 2 7 2002

TC 1700

TE 2800 MAIL ROOK



BEST AVAILABLE COPY

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Atty. Docket: KAGADEI=1

In re Application of:) Conf. No.: 6897

V. KAGADEI et al.) Art Unit: 2838

Appln. No.: 10/086,621) Examiner:

Filed: March 4, 2002) Washington, D.C.

For: A METHOD AND APPARATUS) November 4, 2002 FOR PRODUCING ATOMIC...)

CORRECTED PTO 1449

Honorable Commissioner for Patents Washington, D.C. 20231

Sir:

Regarding with the Information Disclosure Statement filed June 18, 2002, in the above-identified case, there were errors in some the references listed.

Citations AC, AK, AO, AR AT and AU have errors. Please find attached a corrected substitute for form PTO 1449\AA , i.e. PTO/SB/57.

Respectfully submitted, BROWDY AND NEIMARK, P.L.L.C.

Attorneys for Applicant(s)

By

Sheridan Neimark

Registration No. 20,052

SN:lt

Telephone No.: (202) 628-5197
Facsimile No.: (202) 737-3528
G:\BN\C\cohn\Kagadei1\corrected 1449 4NOV.02.doc

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS							
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T ²				
	AC	LEONE, "Kinetic-Energy-Enhanced Neutral Etching", <u>Jpn. J. Appl. Phys.</u> , (1995), vol. 34, No. 4B, pages 2073- 2082					
		ORLIKOVSKY, "Plasma Processes in Micro- and Nanoelectronics Part 1. Reactive Etching", <u>Microelectronics</u> , (1999), vol. 28, No. 5, Pages 344-362	XXX				
		ROUSSEAU et al., "Pulsed microwave discharge: a very efficient H atom source", <u>J. Phys. D: Phys.</u> , (1994), vol 27, pages 2439-2441					
		POPOV et al., "Electron cyclotron resonance plasma stream source for plasma enhanced chemical vapor deposition", <u>J. Vac. Sci. Technol A</u> , (1989), vol. 7, No. 3, pages 914-917					
		KROON, "Removal of Oxygen for the Si(100) Surface in a DC Hydrogen Plasma", <u>Jpn. J. Appl. Phys.,</u> (1997), vol. 36, pages 5068-5071					
		BARDOS et al., "Linear arc discharge source for large area plasma processing", Appl. Phys. Lett, (1997), vol. 70, No. 5, pages 577-579					
		LIPPERT et al., "Soft Cleaning by <i>In Vacuo</i> Ultraviolet Radiation Combined with Molecular Hydrogen Gas before Molecular Beam Epitaxial Layer Growth", <u>J. Electrochem. Soc.</u> , (1995), vol. 142, No. 1, pages 191-195					
	AJ	SUGAYA et al., "Low-Temperature Cleaning of GaAs Substrate by Atomic Hydrogen Irradiation", <u>Japanese</u> <u>Journal of Applied Physics</u> , (1991), vol. 30, No. 3A, pages L402-L404					
		WOLAN et al., "Chemical reactions induced by the room temperature interaction of hyperthermal atomic hydrogen with the native oxide layer on GaAs(001) surfaces studied by ion scattering spectroscopy and X-ray photoelectron spectroscopy", J. Vac. Sci. Technol., (1997), vol 15, No. 5, pages 2502-2507					
		KORZEC et al. "Characterization of a slot antenna microwave plasma source for hydrogen plasma cleaning", <u>J. Vac. Sci Technol.</u> , (1995), vol. 13, No. 4, page 2074-2085					
	AM	EPI MBE Production Group. Aug./Sept., 1994, Applications Note, "On the Use of Atomic Hydrogen in MBE"					
	AN	Application Note, "Cracking Efficiency of the EPI Atomic Hydrogen Source", EPI, January, 1996, No. 1/96					
		HECEIV					
Examir Signatu		Date Considered NOV 2.7 20					

^{*} EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² Applicant is to place a check mark here if English language Translation is attached.

		ייכ				
Substitute for form 1449A/PTO				Complet if Known		
	RMATION D	OV 0	4 2002 ju	Application Numb r	10/086,621	
INFO	RMATION D	ISC	CLOSPRE	Filing Date	March 4, 2002	
STAT	EMENT BY	AP	PLIØÄNT	First Named Inventor	V. KAGADEI et al.	
STATEMENT BY APPLICANT				Group Art Unit		
	(use as many sheet			Examiner Name		
Sheet	3	of	3	Attorney Docket Number	KAGADEI=1	
	<u> </u>					

		OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T²
	AO	LIVSHITS et al., "Dissociation of hydrogen molecules on Metal filaments in H' ion sources", <u>Plasma Cource Sci. Technol.</u> , (1994), pages 465-472	
	AP	HOFLUND et al., "Performance Characteristics of a hyperthermal oxygen-atom generator", Meas. Sci. Technol., (1994), vol 5, pages 201-204	
	AQ	MERFY et al., "Convenient source with a SHF-discharge in an elongated resonator for producing streams of hydrogen atoms" Devices for Scientific Investigations, (1979), vol. 5, Pages 121-122	XXX
	AR	GEDDES et al., "Dissociation for hydrogen in High frequency discharges", Plasma Source Sci. Technol., (1993), vol. 2, pages 93-99	
	AS	RF Gas Cracker/Reactives Atom Source - HD Series, The product of Oxford Applied Research	
	AT	GOODMAN et al., "Ar, N₂, and Cl₂ electron cyclotron resonance plasma measured by time-of-flight analysis: Neutral kinetic energies and source gas cracking", <u>J. Vac. Sci. Technol,</u> (1997), B vol. 15, No. 4, pages 971-982	,
	AU	SHERMAN, "In Situ removal of native oxide from silicon wafers", <u>J. Vac. Sci. Technol.</u> , B vol. 8, No. 4, pages 656-657	
···	AV	SAMANO et al., "An arc discharge hydrogen atom source", <u>Rev. Sci. Instrum.</u> , (1993), vol. 64, No. 10, pages 2746-2752	
	AW	GOURRIER et al., "Growth of Dielectric Films of Semiconductors and Metals Using a Multipole Plasma", <u>Thin Solid Films</u> , (1981), vol. 84, Pages 379-388	
	AY	Handbook of Ion Sources, Ed. by Bernard Wolf, CRC Press, (1995), Pages 32-34, 54-56, 61, 69-71, 222-223	
	AZ	GABOVICH et al., "Out of plasma with high concentration of concentration of charged particles into vacuum", Journal of Technical Physics, (1961), vol. 31, No. 9, Pages 1049-1055	XXX
	ВА	ITO et al., "Purification of diamond films by applying current into the plasma stream in the arc discharge plasma jet chemical vapor deposition technique", <u>J. Appl. Phys.</u> , (1995), vol. 77, No. 12, Pages 6636-6640	

		DECENTE
Examiner Signature	Date Considered	NECEIVED
		NOV 2:7 2002

TC 1700

^{*} EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² Applicant is to place a check mark here if English language Translation is attached.